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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO
09/749,989 12/26/2000		Eric R. Fossum	06816/051002/CIT2247-C1 6859	
20985 75	90 08/03/2004		EXAMINER	
	ARDSON, PC		HERNANDEZ	, NELSON D
12390 EL CAMINO REAL SAN DIEGO, CA 92130-2081			ART UNIT	PAPER NUMBER
Dan Diego, V	31. 32133 2301		2612	

Please find below and/or attached an Office communication concerning this application or proceeding.

1						
	Application No.	Applicant(s)				
•	09/749,989	FOSSUM ET AL.				
Office Action Summary	Examiner	Art Unit				
	Nelson D. Hernandez	2612				
The MAILING DATE of this communication ap Period for Reply	pears on the cover sheet with the c	orrespondence address				
A SHORTENED STATUTORY PERIOD FOR REPL THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1. after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a req If NO period for reply is specified above, the maximum statutory period Failure to reply within the set or extended period for reply will, by statut Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	136(a). In no event, however, may a reply be tin ply within the statutory minimum of thirty (30) day I will apply and will expire SIX (6) MONTHS from te, cause the application to become ABANDONE	nely filed /s will be considered timely. Ithe mailing date of this communication. ED (35 U.S.C. § 133).				
Status						
1) Responsive to communication(s) filed on 20 F	February 2001.					
	is action is non-final.					
	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.					
Disposition of Claims						
4) ⊠ Claim(s) <u>1-33</u> is/are pending in the application 4a) Of the above claim(s) is/are withdra 5) □ Claim(s) is/are allowed. 6) ⊠ Claim(s) <u>1-24 and 26-33</u> is/are rejected. 7) ⊠ Claim(s) <u>25</u> is/are objected to. 8) □ Claim(s) are subject to restriction and/	awn from consideration.					
Application Papers						
9) ☐ The specification is objected to by the Examin 10) ☑ The drawing(s) filed on 26 December 2000 is/ Applicant may not request that any objection to the Replacement drawing sheet(s) including the correct 11) ☐ The oath or declaration is objected to by the E	are: a) \square accepted or b) \square object e drawing(s) be held in abeyance. Section is required if the drawing(s) is ob	e 37 CFR 1.85(a). jected to. See 37 CFR 1.121(d).				
Priority under 35 U.S.C. § 119		•				
12) Acknowledgment is made of a claim for foreign a) All b) Some * c) None of: 1. Certified copies of the priority document 2. Certified copies of the priority document 3. Copies of the certified copies of the priority document application from the International Bureat* See the attached detailed Office action for a list	nts have been received. Its have been received in Applicationity documents have been received au (PCT Rule 17.2(a)).	ion No ed in this National Stage				
Attachment(s)						
1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948)	4) 🔲 Interview Summary Paper No(s)/Mail Da					
 2) Notice of Draftsperson's Patent Drawing Review (P10-948) 3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08 Paper No(s)/Mail Date 12/26/2000. 	_	Patent Application (PTO-152)				

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DETAILED ACTION

Double Patenting

1. The nonstatutory double patenting rejection is based on a judicially created doctrine grounded in public policy (a policy reflected in the statute) so as to prevent the unjustified or improper timewise extension of the "right to exclude" granted by a patent and to prevent possible harassment by multiple assignees. See *In re Goodman*, 11 F.3d 1046, 29 USPQ2d 2010 (Fed. Cir. 1993); *In re Longi*, 759 F.2d 887, 225 USPQ 645 (Fed. Cir. 1985); *In re Van Ornum*, 686 F.2d 937, 214 USPQ 761 (CCPA 1982); *In re Vogel*, 422 F.2d 438, 164 USPQ 619 (CCPA 1970);and, *In re Thorington*, 418 F.2d 528, 163 USPQ 644 (CCPA 1969).

A timely filed terminal disclaimer in compliance with 37 CFR 1.321(c) may be used to overcome an actual or provisional rejection based on a nonstatutory double patenting ground provided the conflicting application or patent is shown to be commonly owned with this application. See 37 CFR 1.130(b).

Effective January 1, 1994, a registered attorney or agent of record may sign a terminal disclaimer. A terminal disclaimer signed by the assignee must fully comply with 37 CFR 3.73(b).

2. Claims 1-21, 24 and 27-33 are rejected under the judicially created doctrine of obviousness-type double patenting as being unpatentable over claims 1-30 of U.S. Patent No. 6,166,768. Although the conflicting claims are not identical, they are not patentably distinct from each other because the reasons discussed below.

Claims 1-3, 19 and 21 is a broader recitation of the same invention claimed in patent claims 1-3, 19 and 21 respectively. The claims are substantially the same except that "photogate" in the patent has been replaced with "photodetector" in the application. Since photodetector is a broader term than photogate, the application claims are encompassed by the patent claims.

Claims 4, 6-11, 14-18 and 20 are substantially the same as in the patent claims 4, 6-11, 14-18 and 20 respectively.

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Claim 5 is a broader recitation of the same invention claimed in patent claim 5. The claim is substantially the same except that "sensing node" in the patent has been replaced with "floating gate of said transistor" in the application. "Sensing node" in patent claim is referring to the floating gate of the transistor as in patent claim 5. Therefore, the application claim is encompassed by the patent claim.

Claim 12 is a broader recitation of the same invention claimed in patent claim 12. The claim is substantially the same except that "plural load transistors and plural correlated double sampling circuits" in the patent has been replaced with "plurality of load transistors and correlated double sampling circuits" in the application. The application claim is encompassed by the patent claim.

Claim 13 is a broader recitation of the same invention claimed in patent claim 13. The claim is substantially the same except that "bottom" in the patent has been replaced with "end" in the application. The application claim is encompassed by the patent claim.

Claim 24 is substantially the same as in the patent claim 23.

Claim 27 is a broader recitation of the same invention claimed in patent claim 24. The claim is substantially the same except that "photogate" in the patent has been replaced with "photodetector" in the application. Since photodetector is a broader term than photogate, the application claim is encompassed by the patent claim.

Claim 28 is substantially the same as in the patent claim 25.

Claim 29 is substantially the same as in the patent claim 26.

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Claim 30 is a broader recitation of the same invention claimed in patent claim 27. The claim is substantially the same except that "photogate" in the patent has been replaced with "photodetector" in the application. Since photodetector is a broader term than photogate, the application claim is encompassed by the patent claim

Claim 31 is substantially the same as in the patent claim 28. Therefore a terminal disclaimer is necessary to ensure that any two resultant patents are commonly owned.

Claim 32 is a broader recitation of the same invention claimed in patent claim 29. The claim is substantially the same except that "photogate" in the patent has been replaced with "photodetector" in the application. Since photodetector is a broader term than photogate, the application claim is encompassed by the patent claim.

Claim 33 is substantially the same as in the patent claim 30.

Since claims 1-21, 24 and 27-33 in the application claims are encompassed by the patent claims. Therefore a terminal disclaimer is necessary to ensure that any two resultant patents are commonly owned.

3. Claim 22, 23 and 26 are rejected under the judicially created doctrine of obviousness-type double patenting as being unpatentable over claim 22 of U.S. Patent No. 6,166,768 in view of Martin, US Patent 6,243,131 B1.

Regarding claims 22 and 23, claim 23 is substantially the same as in the patent claim 30. It is noted that claim 23 depends on claim 22, wherein the limitations of having the first diffusion region is a floating node operating as a

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source of the pixel transistor and that the second diffusion region is biased at a selected DC voltage to function as a drain in claim 22 are not claimed in the patent.

However, Martin teaches the structure of an active pixel sensor (Fig. 6) wherein the pixel contains a transfer gate (Fig. 6: 601) and a floating-diffusion source follower output amplifier. The pixel source follower section converts the photogenerated signal output into a voltage at a junction (Fig. 6: 602). Martin also teaches a second diffusion region biased at a selected DC voltage to function as a drain in fig. 6 (Col. 10, lines 22-50).

Therefore, it would have been obvious to one of ordinary skill in the art at the time of the invention was made to have a floating-diffusion source follower output amplifier to convert the photogenerated signal output into an electronic signal and have a second diffusion region biased at a selected DC voltage to function as a drain with the motivation of making an active pixel sensor having a built-in output amplification as suggested by Martin (Col. 10, lines 32-45).

Regarding claim 26, the limitations of having a circuit comprising a field-effect source follower output transistor formed in each one of the cells, the second region of said pixel transistor being connected to a gate of said source follower output transistor; a field-effect load transistor connected to said source follower output transistor; and a correlated double sampling circuit having an input node connected between said source follower output transistor and said load transistor and operable to sample said second diffusion region twice in an

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readout operation to produce an output signal indicating only said photogenerated charge are not claim in the patent.

However, Martin teaches the structure of an active pixel sensor (Fig. 6) wherein the pixel contains a transfer gate (Fig. 6: 601) and a floating-diffusion source follower output amplifier. The pixel source follower section converts the photogenerated signal output into a voltage at a junction (Fig. 6: 602). Martin also teaches a second diffusion region biased at a selected DC voltage to function as a drain in fig. 6. Also teaches a field-effect load transistor (Fig. 6: MLM) connected to the source follower output transistor (Col. 10, lines 35-39). In fig. 6, Martin also teaches a correlated double sampling circuit having an input node connected between said source follower output transistor and said load transistor and operable to sample said second diffusion region twice in an readout operation to produce an output signal indicating only said photogenerated signal (Fig. 6; col. 10, lines 22-63).

Therefore, it would have been obvious to one of ordinary skill in the art at the time of the invention to have a circuit comprising a field-effect source follower output transistor formed in each one of the cells, the second region of said pixel transistor being connected to a gate of said source follower output transistor, a field-effect load transistor connected to the source follower output transistor and a correlated double sampling circuit having an input node connected between said source follower output transistor and said load transistor and operable to sample said second diffusion region twice in an readout operation. The motivation to do so would enable making an active pixel sensor having built-in

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output amplification and to suppress fixed pattern noise from the signal due to threshold voltage offset, inn order to provide a distortion corrected image without requiring the use of distortion correction circuitry as suggested in Martin (Col. 3, lines 60-67).

Allowable Subject Matter

4. Claim 25 is objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

Contact

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Nelson D. Hernandez whose telephone number is (703) 305-8717. The examiner can normally be reached on 8:30 A.M. to 6:00 P.M..

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Wendy R. Garber can be reached on (703) 305-4929. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

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Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Nelson D. Hernandez Examiner Art Unit 2612

NDHH July 19, 2004

> TUAN HO PRIMARY EXAMINER